

TECHNICAL DATA
DATA SHEET 4545, REV. –**HERMETIC POWER SCHOTTKY RECTIFIER**
Very Low Forward Voltage Drop**Applications:**

- Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Very Low Forward Voltage Drop
- High Efficiency
- High Frequency Application
- Guard Ring for Enhanced Durability and Long Term Reliability

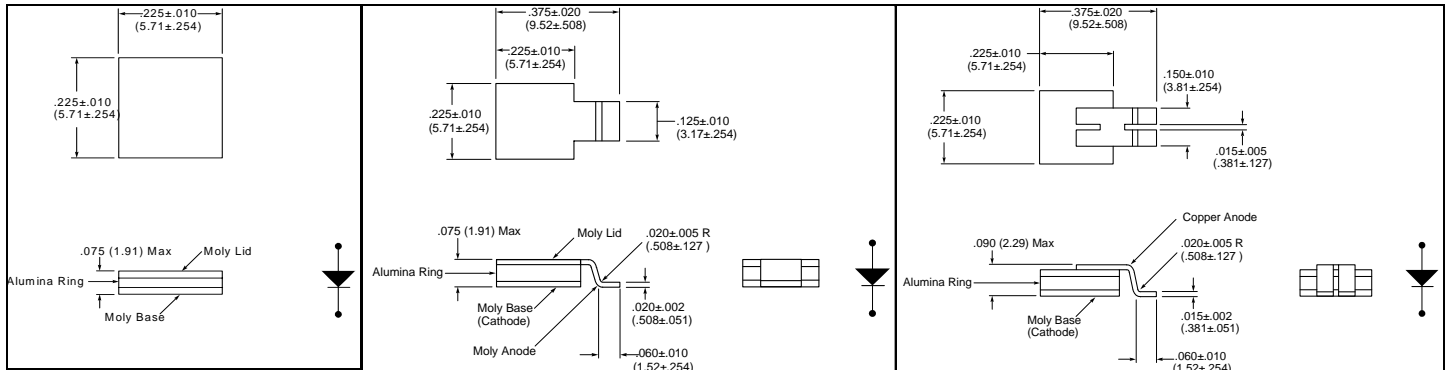
MAXIMUM RATINGSALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_O	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine)	I_{FSM}	250	Amps
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	1.67	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	T_{op}	-65 to + 150	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	T_{stg}	-65 to + 150	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15\text{ Amps}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.90 0.72	Volts
MAXIMUM REVERSE CURRENT ($I_r @ 100\text{V PIV}$) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.5 15	mA
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	600	pF

MECHANICAL DIMENSIONS: In Inches / mm



SHD-1

SHD-1A

SHD-1B

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